# **BOURNS®**

- Designed for Complementary Use with the TIP42 Series
- 65 W at 25°C Case Temperature
- 6 A Continuous Collector Current
- 10 A Peak Collector Current
- Customer-Specified Selections Available

# B 1 2 E 3

Pin 2 is in electrical contact with the mounting base.

MDTRACA

# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING   |                 |                  | VALUE       | UNIT |
|--|-----------------|------------------|-------------|------|
|  | TIP41           |                  | 80          |      |
| Collector-base voltage ( $I_E = 0$ )   | TIP41A          | V                | 100         | V    |
|  | TIP41B          | V <sub>CBO</sub> | 120         | ٧    |
|  | TIP41C          |                  | 140         |      |
|  | TIP41           |                  | 40          |      |
| Callegtor emitter voltage (I = 0)  | TIP41A          | V                | 60          | V    |
| Collector-emitter voltage (I <sub>B</sub> = 0)                                     | TIP41B          | V <sub>CEO</sub> | 80          |      |
|  | TIP41C          |                  | 100         |      |
| Emitter-base voltage   |                 |                  | 5           | V    |
| Continuous collector current   |                 |                  | 6           | Α    |
| Peak collector current (see Note 1)  | I <sub>CM</sub> | 10               | Α           |      |
| Continuous base current  |                 |                  | 3           | Α    |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2)     |                 |                  | 65          | W    |
| Continuous device dissipation at (or below) 25°C free air temperature (see Note 3) |                 |                  | 2           | W    |
| Unclamped inductive load energy (see Note 4)                                       |                 |                  | 62.5        | mJ   |
| Operating junction temperature range   |                 |                  | -65 to +150 | °C   |
| Storage temperature range  |                 |                  | -65 to +150 | °C   |
| Lead temperature 3.2 mm from case for 10 seconds                                   |                 |                  | 250         | °C   |

NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .

- 2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 0.4 A,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



# electrical characteristics at 25°C case temperature

| PARAMETER            |   | TEST CONDITIONS  |   |                                     | MIN                   | TYP | MAX                      | UNIT |
|----------------------|---|--|---|-------------------------------------|-----------------------|-----|--------------------------|------|
| V <sub>(BR)CEO</sub> | Collector-emitter breakdown voltage         | I <sub>C</sub> = 30 mA<br>(see Note 5)   | I <sub>B</sub> = 0                                  | TIP41<br>TIP41A<br>TIP41B<br>TIP41C | 40<br>60<br>80<br>100 |     |                          | V    |
| I <sub>CES</sub>     | Collector-emitter cut-off current           | $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$ $V_{CE} = 120 \text{ V}$ $V_{CE} = 140 \text{ V}$ | $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ | TIP41<br>TIP41A<br>TIP41B<br>TIP41C |                       |     | 0.4<br>0.4<br>0.4<br>0.4 | mA   |
| I <sub>CEO</sub>     | Collector cut-off current                   | $V_{CE} = 30 \text{ V}$ $V_{CE} = 60 \text{ V}$  | I <sub>B</sub> = 0<br>I <sub>B</sub> = 0            | TIP41/41A<br>TIP41B/41C             |                       |     | 0.7<br>0.7               | mA   |
| I <sub>EBO</sub>     | Emitter cut-off current                     | V <sub>EB</sub> = 5 V  | I <sub>C</sub> = 0                                  |                                     |                       |     | 1                        | mA   |
| h <sub>FE</sub>      | Forward current transfer ratio              | $V_{CE} = 4 V$ $V_{CE} = 4 V$  | $I_{\rm C} = 0.3  {\rm A}$ $I_{\rm C} = 3  {\rm A}$ | (see Notes 5 and 6)                 | 30<br>15              |     | 75                       |      |
| V <sub>CE(sat)</sub> | Collector-emitter saturation voltage        | I <sub>B</sub> = 0.6 A   | I <sub>C</sub> = 6A                                 | (see Notes 5 and 6)                 |                       |     | 1.5                      | V    |
| $V_{BE}$             | Base-emitter voltage                        | V <sub>CE</sub> = 4 V  | I <sub>C</sub> = 6 A                                | (see Notes 5 and 6)                 |                       |     | 2                        | V    |
| h <sub>fe</sub>      | Small signal forward current transfer ratio | V <sub>CE</sub> = 10 V   | I <sub>C</sub> = 0.5 A                              | f = 1 kHz                           | 20                    |     |                          |      |
| h <sub>fe</sub>      | Small signal forward current transfer ratio | V <sub>CE</sub> = 10 V   | I <sub>C</sub> = 0.5 A                              | f = 1 MHz                           | 3                     |     |                          |      |

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2\%$ .

# thermal characteristics

| PARAMETER       |   |  | TYP | MAX  | UNIT |
|-----------------|---|--|-----|------|------|
| $R_{\theta JC}$ | Junction to case thermal resistance     |  |     | 1.92 | °C/W |
| $R_{\theta JA}$ | Junction to free air thermal resistance |  |     | 62.5 | °C/W |

# resistive-load-switching characteristics at 25°C case temperature

|                  | PARAMETER     | TEST CONDITIONS †    |                     |                                  | MIN | TYP | MAX | UNIT |
|------------------|---------------|----------------------|---------------------|----------------------------------|-----|-----|-----|------|
| t <sub>on</sub>  | Turn-on time  | I <sub>C</sub> = 6 A | $I_{B(on)} = 0.6 A$ | I <sub>B(off)</sub> = -0.6 A     |     | 0.6 |     | μs   |
| t <sub>off</sub> | Turn-off time | $V_{BE(off)} = -4 V$ | $R_L = 5 \Omega$    | $t_p = 20 \ \mu s, \ dc \le 2\%$ |     | 1   |     | μs   |

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### **TYPICAL CHARACTERISTICS**

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS633AD 1000 V<sub>CE</sub> = 4 V $T_c = 25^{\circ}C$ $t_p = 300 \mu s$ , duty cycle < 2%h<sub>FE</sub> - DC Current Gain 100 10 1.0 0.01 0.1 1.0 10 I<sub>c</sub> - Collector Current - A

Figure 1.

# COLLECTOR-EMITTER SATURATION VOLTAGE vs BASE CURRENT TCS633AE

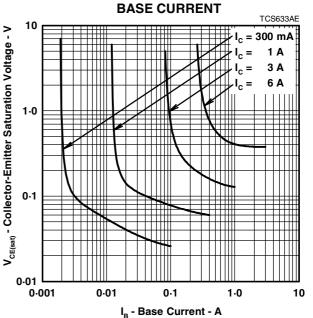


Figure 2.

# BASE-EMITTER VOLTAGE

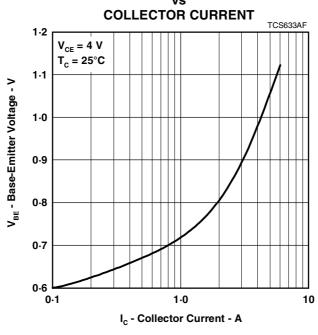
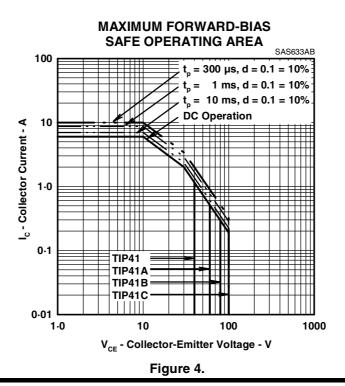


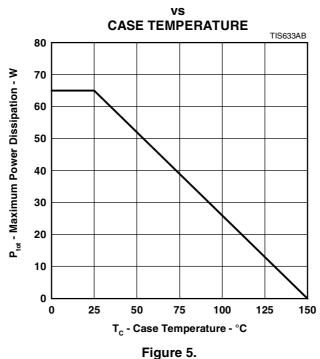
Figure 3.

#### **MAXIMUM SAFE OPERATING REGIONS**



### THERMAL INFORMATION

#### **MAXIMUM POWER DISSIPATION**



## PRODUCT INFORMATION